

2SK3476

VHF- and UHF-band Amplifier Applications

(Note)The TOSHIBA products listed in this document are intended for high frequency Power Amplifier of telecommunications equipment. These TOSHIBA products are neither intended nor warranted for any other use. Do not use these TOSHIBA products listed in this document except for high frequency Power Amplifier of telecommunications equipment.

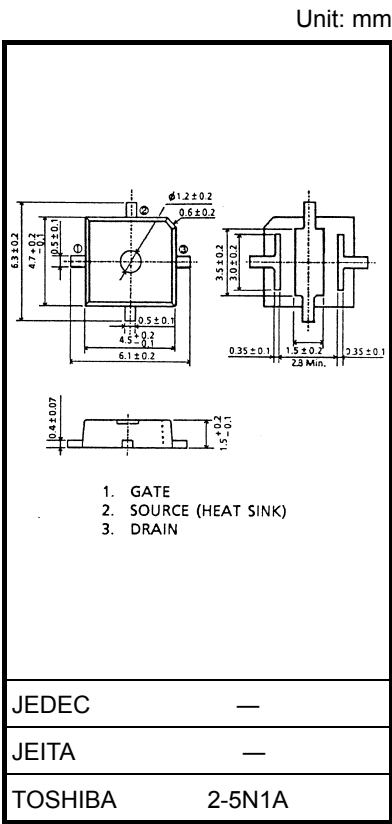
- Output power:  $P_O = 7.0\text{ W (min)}$
- Gain:  $G_P = 11.4\text{ dB (min)}$
- Drain efficiency:  $\eta_D = 60\% \text{ (min)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	20	V
Gate-source voltage	$V_{GSS}$	10	V
Drain current	$I_D$	3	A
Power dissipation	$P_D$ (Note 1)	20	W
Channel temperature	$T_{ch}$	150	°C
Storage temperature range	$T_{stg}$	-45~150	°C

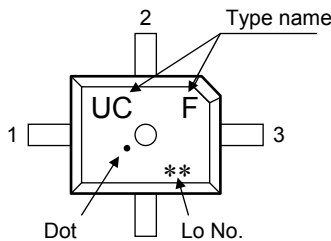
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $T_c = 25^\circ\text{C}$  (When mounted on a 1.6 mm glass epoxy PCB)



Weight: 0.08 g (typ.)

Marking



1. Gate
2. Source (heat sink)
3. Drain

Caution

Please take care to avoid generating static electricity when handling this transistor.

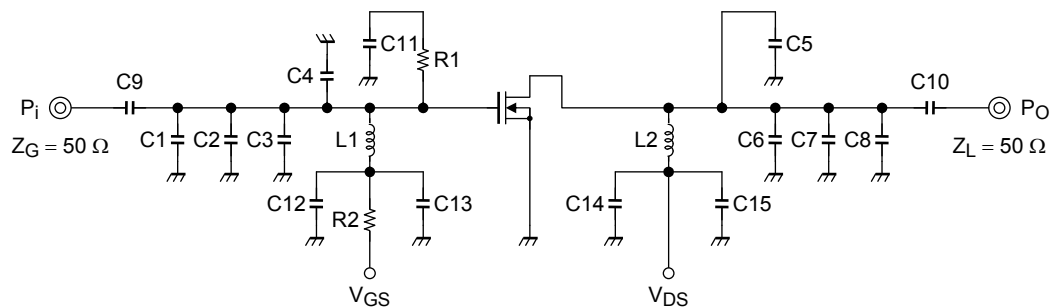
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20\text{ V}$ , $V_{GS} = 0\text{ V}$	—	—	5	$\mu\text{A}$
Gate-source leakage current	$I_{GSS}$	$V_{GS} = 5\text{ V}$	—	—	5	$\mu\text{A}$
Threshold voltage	$V_{th}$	$V_{DS} = 7.2\text{ V}$ , $I_D = 2\text{ mA}$	0.55	1.05	1.55	V
Drain-source on-voltage	$V_{DS(ON)}$	$V_{GS} = 10\text{ V}$ , $I_D = 75\text{ mA}$	—	18	—	mV
Forward transconductance	$Y_{fs}$	$V_{DS} = 7.2\text{ V}$ , $I_{DS} = 1\text{ A}$	—	1	—	S
Input capacitance	$C_{iss}$	$V_{DS} = 7.2\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$	—	53	—	pF
Output capacitance	$C_{oss}$	$V_{DS} = 7.2\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$	—	49	—	pF
Output power	$P_O$	$V_{DS} = 7.2\text{ V}$ , $I_{idle} = 500\text{ mA}$ ( $V_{GS} = \text{adjust}$ ), $f = 520\text{ MHz}$ , $P_i = 500\text{ mW}$ ,	7	—	—	W
Drain efficiency	$\eta_D$		60	—	—	%
Power gain	$G_p$		11.4	—	—	dB
Low voltage output power	$P_{OL}$	$V_{DS} = 6.0\text{ V}$ , $I_{idle} = 500\text{ mA}$ ( $V_{GS} = \text{adjust}$ ), $f = 520\text{ MHz}$ , $P_i = 500\text{ mW}$ ,	5	—	—	W
Load mismatch	—	$V_{DS} = 10\text{ V}$ , $P_O = 7\text{ W}$ , $V_{GS} = \text{adjust}$ , $P_i = \text{adjust}$ , $f = 520\text{ MHz}$ , VSWR LOAD 20:1 all phase	No degradation			

Note 1: These characteristic values are measured using measurement tools specified by Toshiba.

### Output Power Test Fixture

(Test Condition:  $f = 520\text{ MHz}$ ,  $V_{DS} = 7.2\text{ V}$ ,  $I_{idle} = 500\text{ mA}$ ,  $P_i = 500\text{ mW}$ )



C1: 15 pF

C2: 11 pF

C3: 9 pF

C4: 30 pF

C5: 30 pF

C6: 11 pF

C7: 8 pF

C8: 9 pF

C9: 2200 pF

C10: 2200 pF

C11: 2200 pF

C12: 10000 pF

C13: 10  $\mu\text{F}$

C14: 10000 pF

C15: 10  $\mu\text{F}$

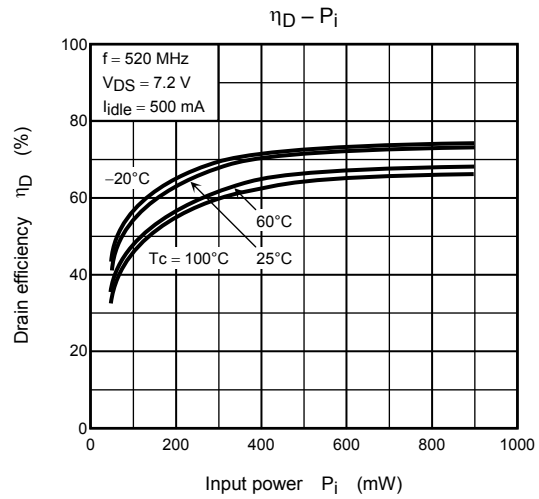
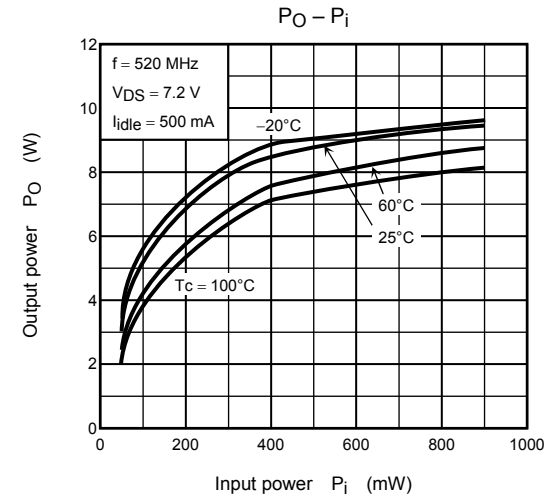
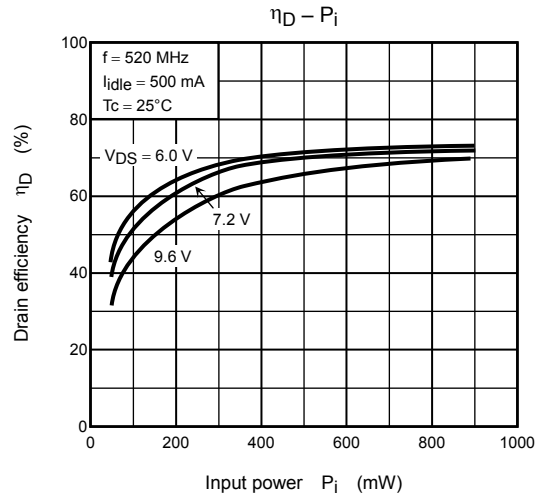
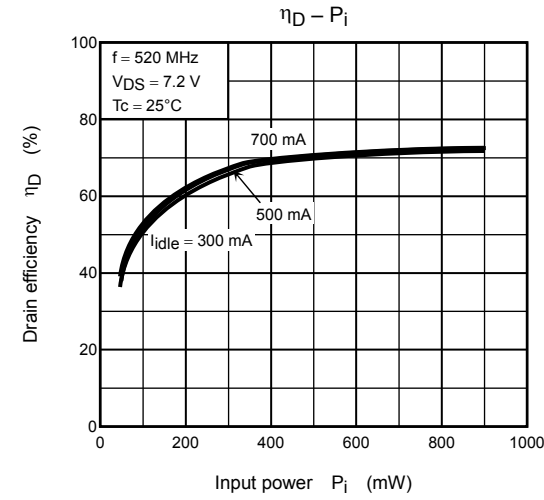
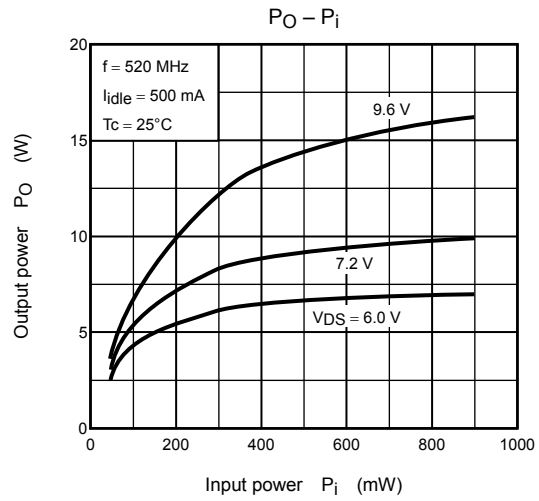
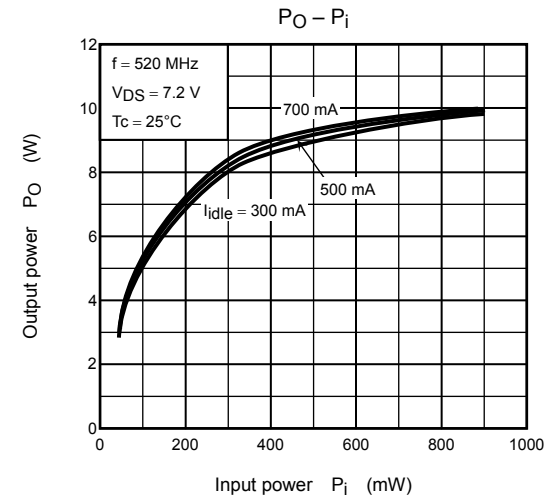
L1:  $\phi 0.6\text{ mm}$  enamel wire, 5.8ID, 4T

L2:  $\phi 0.6\text{ mm}$  enamel wire, 5.8ID, 8T

R1: 2.2  $\Omega$

R2: 1.5 k $\Omega$

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Note 2: These are only typical curves and devices are not necessarily guaranteed at these curves.

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20070701-EN GENERAL

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